NSN 5961-01-436-0048

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-436-0048
Inclosure Material:
Plastic
Overall Length:
Between 0.115 inches and 0.128 inches
Overall Height:
Between 0.046 inches and 0.056 inches
Overall Width:
Between 0.085 inches and 0.108 inches
Overall Diameter:
Between 0.209 inches and 0.230 inches
Internal Configuration:
Junction contact
Mounting Method:
Press fit
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
75.0 collector to base voltage/static/emitter open and 50.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage,
static, collector open
Current Rating Per Characteristic:
800.00 milliamperes source cutoff current
Power Rating Per Characteristic:
1.16 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Test Data Document:
81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
3 bonding pad
Specification Data:
81349-mil-prf-19500/255 government specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli

Mil-prf-19500 spec

Mil-std (military Standard):

Fiig: A110a0